
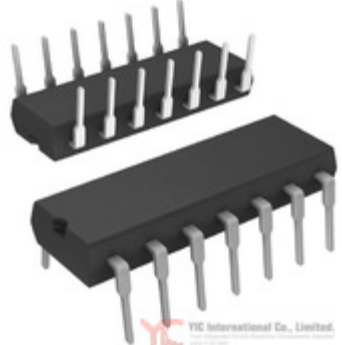
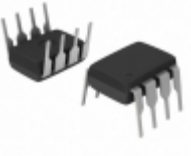
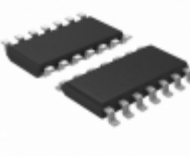
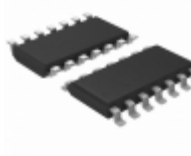
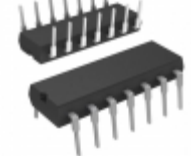


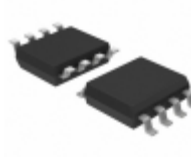
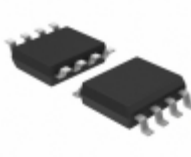
 <p>ADVANCED LINEAR DEVICES, INC.</p>	<h2>ALD1103PBL</h2>
	<p><b>Hersteller-Teilenummer:</b> <a href="#">ALD1103PBL</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Advanced Linear Devices, Inc.</a></p> <p><b>Teil der Beschreibung:</b> MOSFET 2N/2P-CH 10.6V 14DIP</p> <p><b>Datenblätter:</b>  <a href="#">ALD1103PBL.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	ALD1103PBL
Hersteller	Advanced Linear Devices, Inc.
Beschreibung	MOSFET 2N/2P-CH 10.6V 14DIP
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	<a href="#">Require For Quote &amp; Check Stock</a>
VGS (th) (Max) @ Id	1V @ 10μA
Supplier Device-Gehäuse	14-PDIP
Serie	-
Rds On (Max) @ Id, Vgs	75 Ohm @ 5V
Leistung - max	500mW
Verpackung	Tube
Verpackung / Gehäuse	14-DIP (0.300", 7.62mm)
Betriebstemperatur	0°C ~ 70°C (TJ)
Befestigungsart	Through Hole
Eingabekapazität (Ciss) (Max) @ Vds	10pF @ 5V
Gate Charge (Qg) (Max) @ Vgs	-
Typ FET	2 N and 2 P-Channel Matched Pair
FET-Merkmal	Standard
Drain-Source-Spannung (Vdss)	10.6V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	40mA, 16mA

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### Sie können auch interessiert

<p>sein:</p>  <p><b>ALD1102PAL</b> Advanced Linear Devices Inc. MOSFET 2P-CH 10.6V 8DIP</p>	 <p><b>ALD1106SBL</b> Advanced Linear Devices Inc. MOSFET 4N-CH 10.6V 14SOIC</p>	 <p><b>ALD1103SBL</b> Advanced Linear Devices Inc. MOSFET 2N/2P-CH 10.6V 14SOIC</p>	 <p><b>ALD1105PBL</b> Advanced Linear Devices Inc. MOSFET 2N/2P-CH 10.6V 14DIP</p>
 <p><b>ALD1105SBL</b> Advanced Linear Devices Inc. MOSFET 2N/2P-CH 10.6V 14SOIC</p>	 <p><b>ALD1102SAL</b> Advanced Linear Devices Inc. MOSFET 2P-CH 10.6V 8SOIC</p>	 <p><b>ALD1102BSAL</b> Advanced Linear Devices Inc. MOSFET 2P-CH 10.6V 8SOIC</p>	 <p><b>ALD1102ASAL</b> Advanced Linear Devices Inc. MOSFET 2P-CH 10.6V 8SOIC</p>

### Verwandtes Hot-Keyword

Mehr

ALD1103PBL Advanced Linear Devices, Inc.	ALD1103PBL Datenblatt	ALD1103PBL-Datenblätter	ALD1103PBL PDF	Advanced Linear Devices, Inc. ALD1103PBL
ALD1103PBL Electronic	ALD1103PBL-Komponenten	ALD1103PBL-Verteiler	ALD1103PBL-Bild	ALD1103PBL-Teil
ALD1103PBL Preis	ALD1103PBL Hersteller	ALD1103PBL Bild	ALD1103PBL Aktie	ALD1103PBL Inventar
ALD1103PBL Neu	ALD1103PBL Original	ALD1103PBL garantiert	ALD1103PBL RFQ	ALD1103PBL Online bestellen

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HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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